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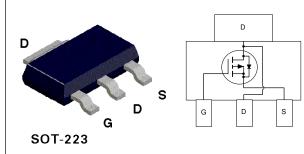
NDT456P P-Channel Enhancement Mode Field Effect Transistor

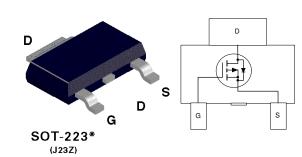
General Description

Power SOT P-Channel enhancement mode power field effect transistors are produced using ON Semiconductor's proprietary, high cell density, DMOS technology. This very high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management, battery powered circuits, and DC motor control.

Features

- $\label{eq:gamma_state} \begin{array}{c} \bullet & -7.5 \mbox{ A}, \mbox{ -30 V}, \mbox{ R}_{_{DS(ON)}} = 0.030 \ \Omega \ @ \mbox{ V}_{_{GS}} = -10 \ V \\ & \mbox{ R}_{_{DS(ON)}} = 0.045 \ \Omega \ @ \ \mbox{ V}_{_{GS}} = -4.5 \ V. \end{array}$
- High density cell design for extremely low R_{DS(ON)}.
- High power and current handling capability in a widely used surface mount package.

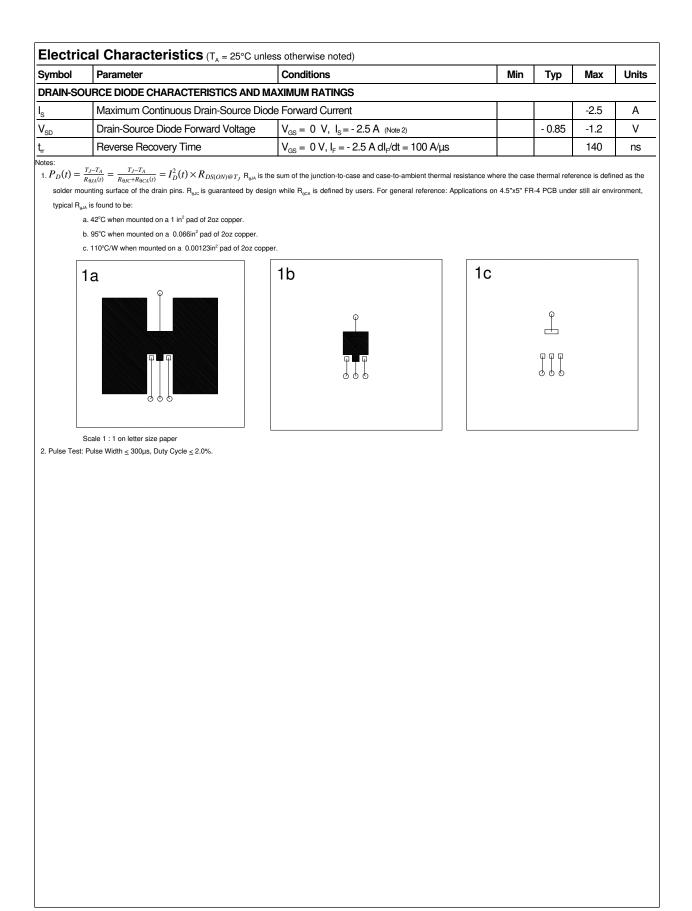


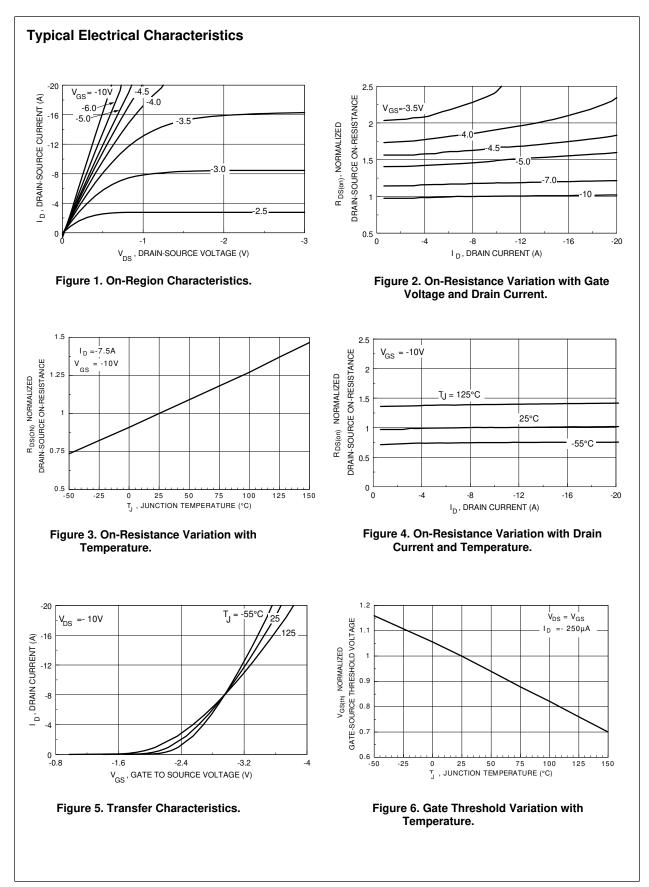


Absolute Maximum Ratings T₄ = 25°C unless otherwise noted

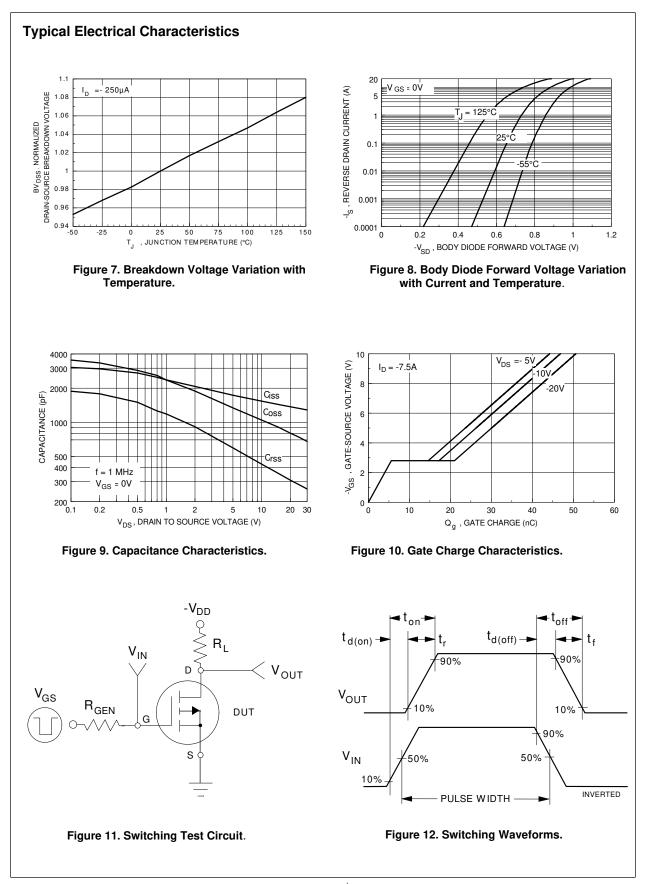
Symbol	Parameter		NDT456P	Units
V _{DSS}	Drain-Source Voltage		-30	V
V_{GSS}	Gate-Source Voltage		±20	V
I _D	Drain Current - Continuous	(Note 1a)	±7.5	A
	- Pulsed		±20	
P _D	Maximum Power Dissipation	(Note 1a)	3	W
		(Note 1b)	1.3	
		(Note 1c)	1.1	
Г _J ,Т _{STG}	Operating and Storage Temperature Range		-65 to 150	C°
THERMA	L CHARACTERISTICS			
R _{eja}	Thermal Resistance, Junction-to-Ambient (Note 1a)		42	°C/W
R _{ØJC}	Thermal Resistance, Junction-to-Ca	ISE (Note 1)	12	°C/W

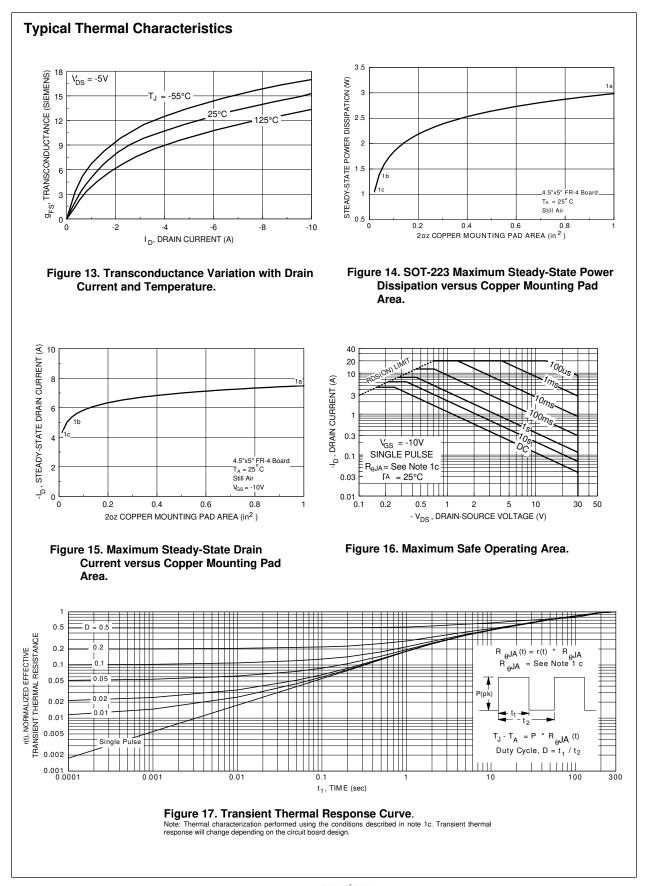
Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHA	RACTERISTICS	•					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = 250 \mu A$		-30			V
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -24 V, V_{GS} = 0 V$				-1	μA
			T _J = 55°C			-10	μA
I _{GSSF}	Gate - Body Leakage, Forward	$V_{GS} = 20 V, V_{DS} = 0 V$	·			100	nA
I _{GSSR}	Gate - Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				-100	nA
ON CHAR	ACTERISTICS (Note 2)					•	•
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		-1	-1.5	-3	V
. /			T _J = 125°C	-0.5	-1.1	-2.6	
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -7.5 \text{ A}$	·		0.026	0.03	Ω
			T _J =125°C		0.035	0.054	
		$V_{GS} = -4.5 \text{ V}, I_{D} = -6 \text{ A}$	·		0.041	0.045	
I _{D(on)}	On-State Drain Current	$V_{GS} = -10 \text{ V}$, $V_{DS} = -5 \text{ V}$		-20			Α
		$V_{GS} = -4.5 \text{ V}, V_{DS} = -5 \text{ V}$		-10			
G _{fs}	Forward Transconductance	$V_{GS} = -10 \text{ V}, \ I_{D} = -7.5 \text{ A}$			13		S
DYNAMIC	CHARACTERISTICS						
C _{iss}	Input Capacitance	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz			1440		pF
C _{oss}	Output Capacitance				905		pF
C _{rss}	Reverse Transfer Capacitance				355		pF
SWITCHIN	IG CHARACTERISTICS (Note 2)					-	
t _{D(on)}	Turn - On Delay Time	$V_{DD} = -15 \text{ V}, \text{ I}_{D} = -7 \text{ A},$ $V_{GEN} = -10 \text{ V}, \text{ R}_{GEN} = 12 \Omega$			10	20	ns
ţ.	Turn - On Rise Time				65	120	ns
D(off)	Turn - Off Delay Time				70	130	ns
t _r	Turn - Off Fall Time				70	130	ns
Q _g	Total Gate Charge	$V_{DS} = -10 \text{ V},$ $I_{D} = -7.5 \text{ A}, V_{GS} = -10 \text{ V}$			47	67	nC
Q _{gs}	Gate-Source Charge				5		nC
Q _{gd}	Gate-Drain Charge				12		nC





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